

A Fully Integrated Micro Mass Spectrometer

Eric Wapelhorst

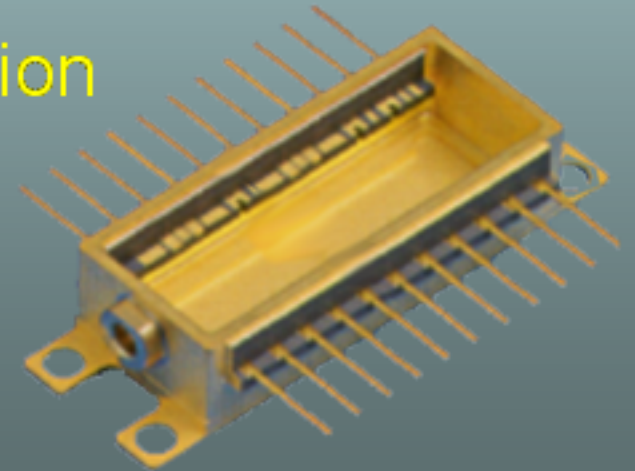
09/22/2005



- ④ Motivation MS in MEMS Technology
- ④ Function Principle of our MMS
- ④ Fabrication
- ④ Conclusion & Outlook

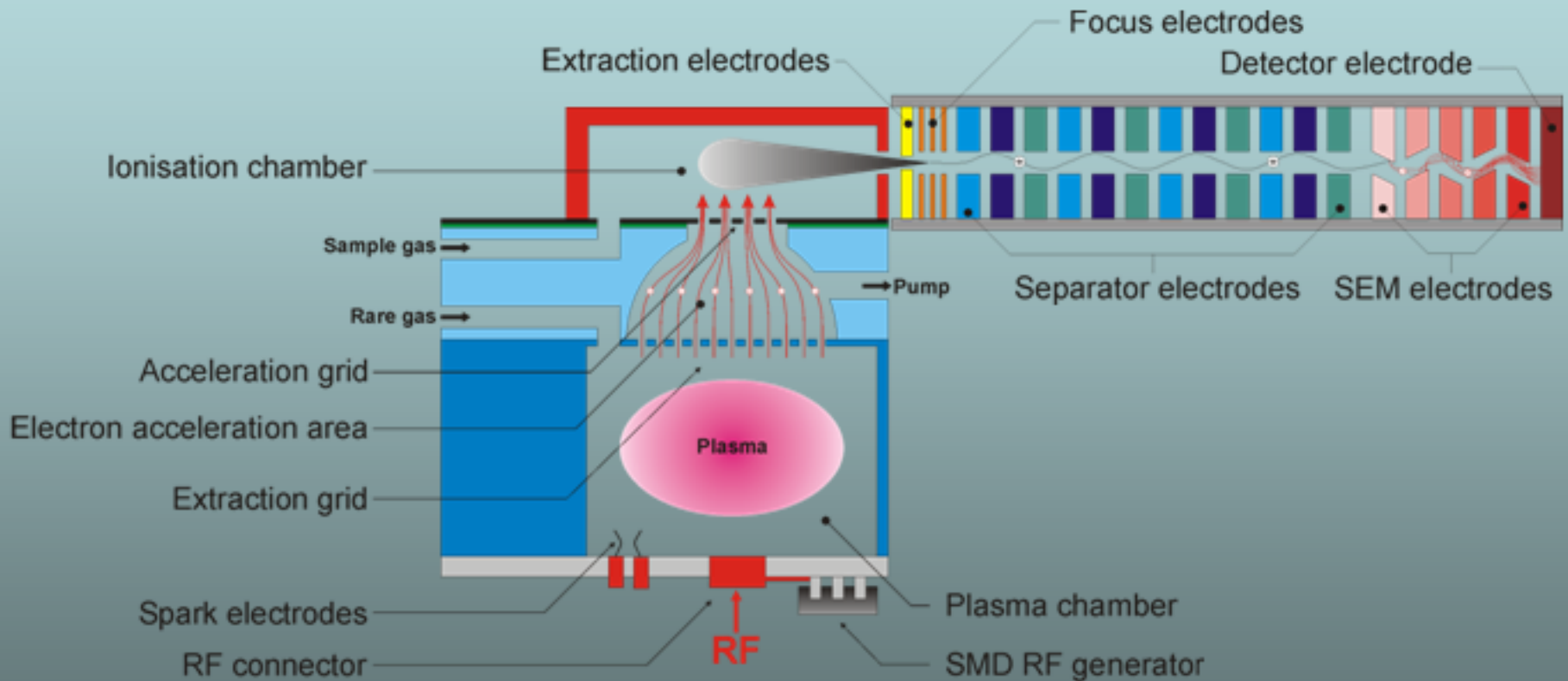
- ④ Gyro Sensors
- ④ Flow Sensors
- ④ Pressure Sensors
- ④ RF Switches
- ④ Print Heads
- ④ Micro Mirrors
- ④ **Micro Mass Spectrometers**

- ④ Small in Size $<5 \times 3 \times 2 \text{ mm}^3$
- ④ Low Power Consumption $<500 \text{ mW}$
- ④ Low Gas Consumption $<0.1 \text{ sccm}$
- ④ Uncritical Vacuum $>1 \text{ Pa}$ ($>7.5 \text{ mTorr}$)
- ④ Wafer Based Standard Processes
 - Cheap in Mass Fabrication



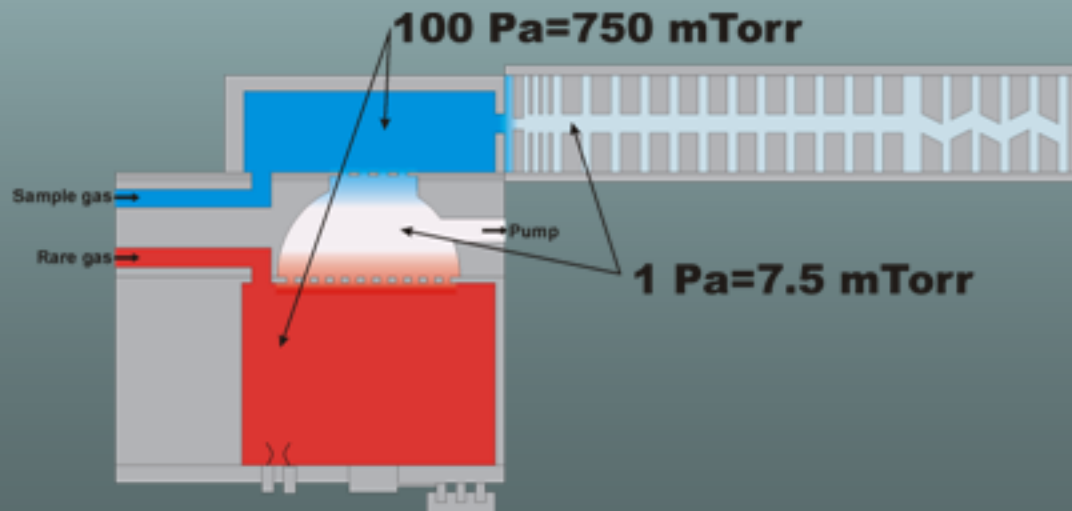
- ④ Rescue Services
- ④ Homeland Security
- ④ Environmental Monitoring
- ④ Process Control
- ④ Automotive Industry



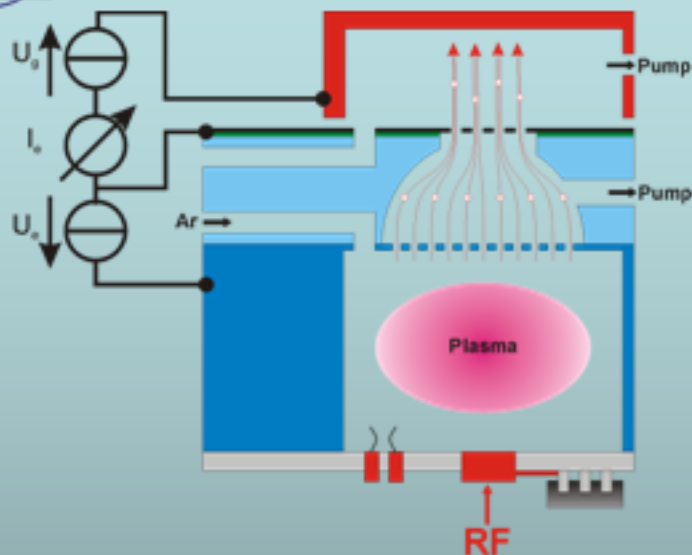


Pressure Regions

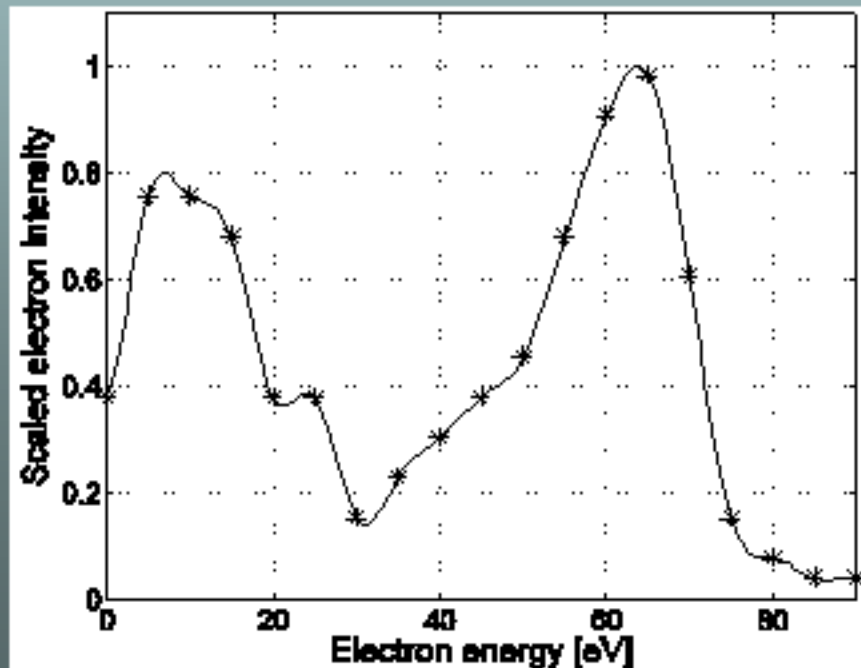
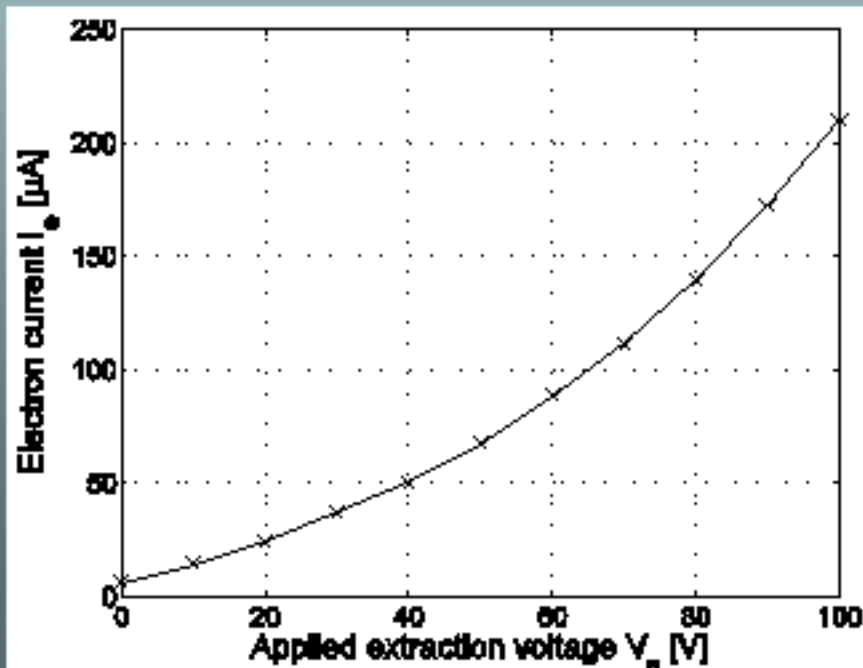
- ④ Mean Free Path $> 3\text{mm}$
- ④ Low Pressure $1\text{Pa} = 7.5\text{mTorr}$
 - One-Stage Pumping System
 - Micro Diffusion Pump
- ④ High Pressure Regions: $100\text{Pa} = 750\text{mTorr}$
- ④ Pressure Apertures, Valves, Gas Flow Sensors



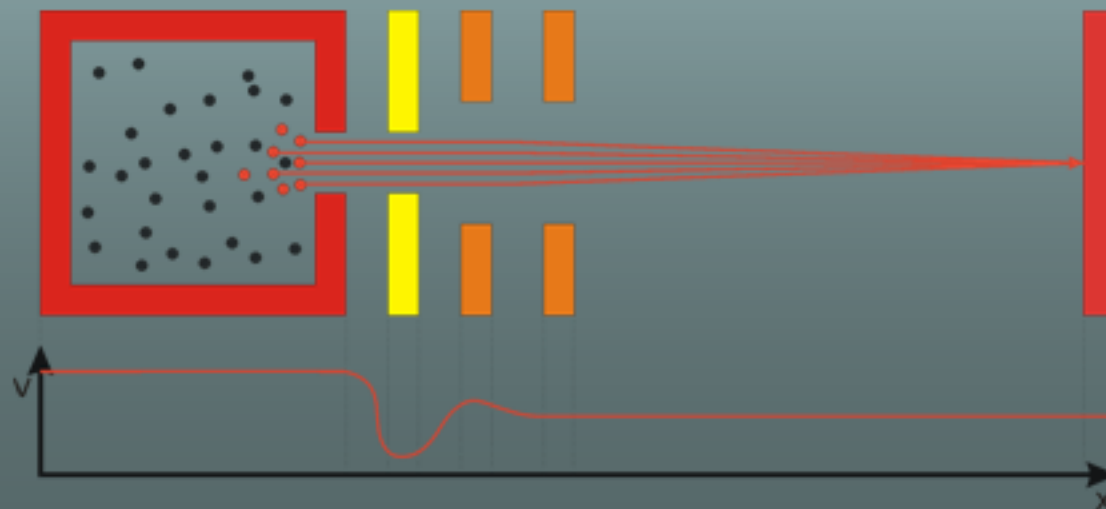
- ④ Electron Source
- ④ Ion Source
- ④ Mass Separator
- ④ SEM



- Ⓜ Stable RF Plasma
 - Constant RF-Power
 - Constant Pressure
- Ⓜ Electron Current Density $1\text{A}/\text{cm}^2$
- Ⓜ Constant $U_e = 70\text{V}$

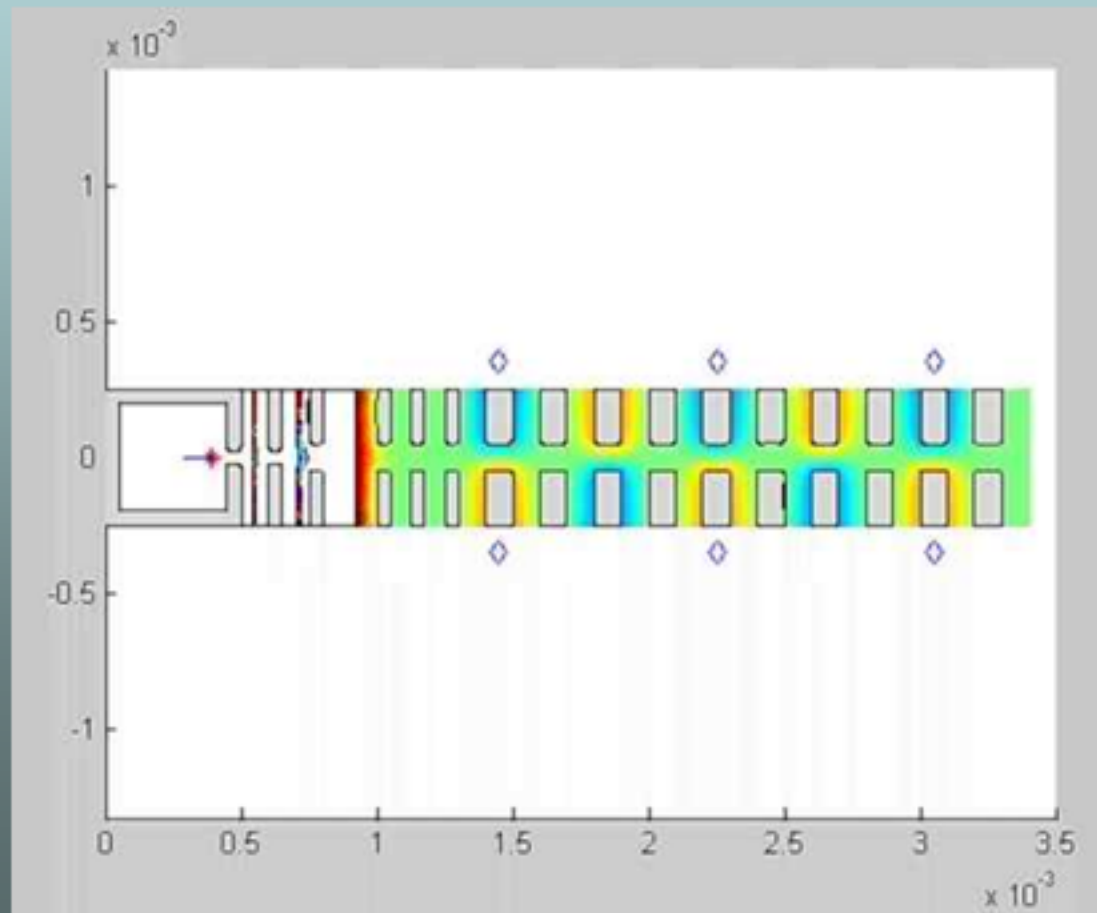


- ④ Small Ionization Area
- ④ Ion Outlet is Pressure Aperture
- ④ Extraction Electrode (Acceleration)
- ④ Focus Electrodes (Deceleration)
- ④ Ion Energy Behind Focus Electrodes 50-100eV
 - Heavy Ions Slower than Light Ones
- ④ Ion Current 5 μ A (Without Mass Separator)

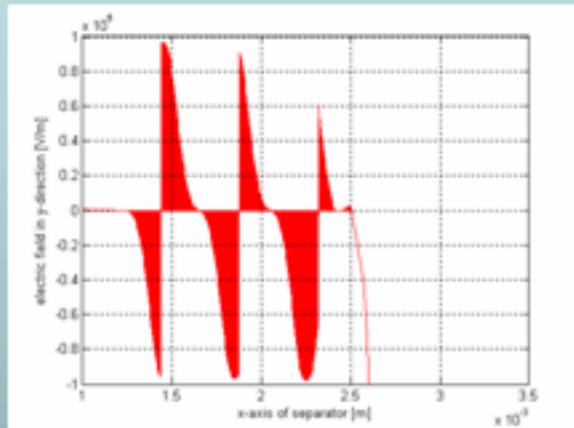


Mass Separator

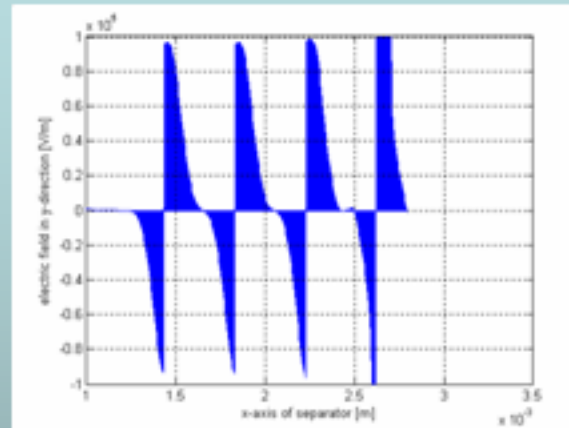
- ④ Traveling Dipole Field (TDF)
- ④ Finger Electrodes



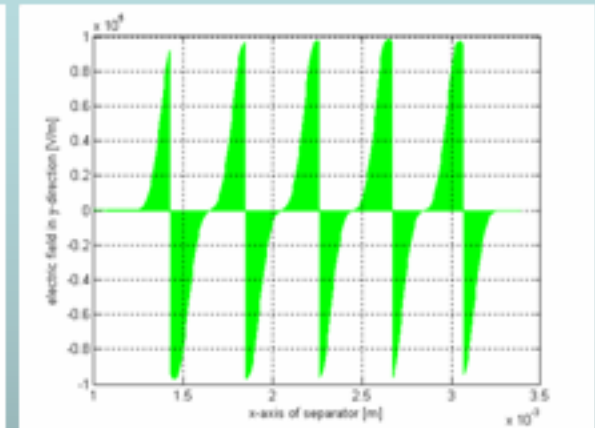
Electrical Field (Ion's Point of View)



Ion Slower than TDF



Ion Faster than TDF

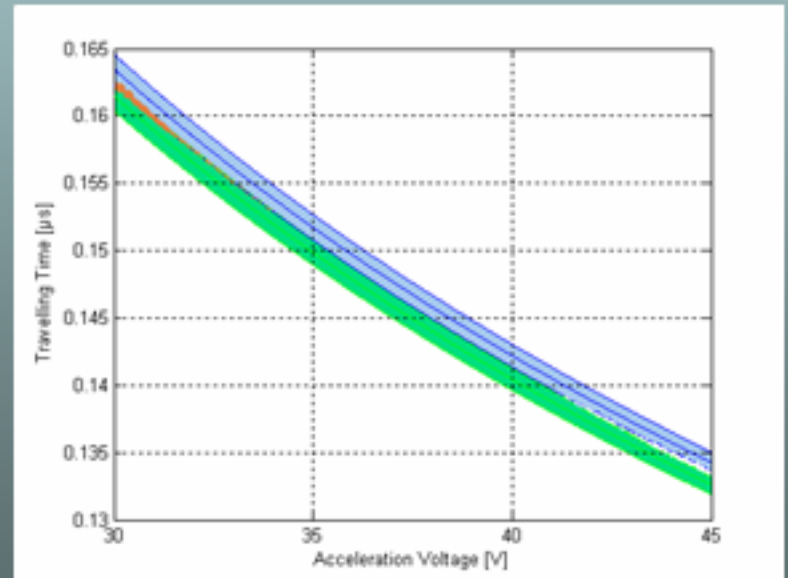
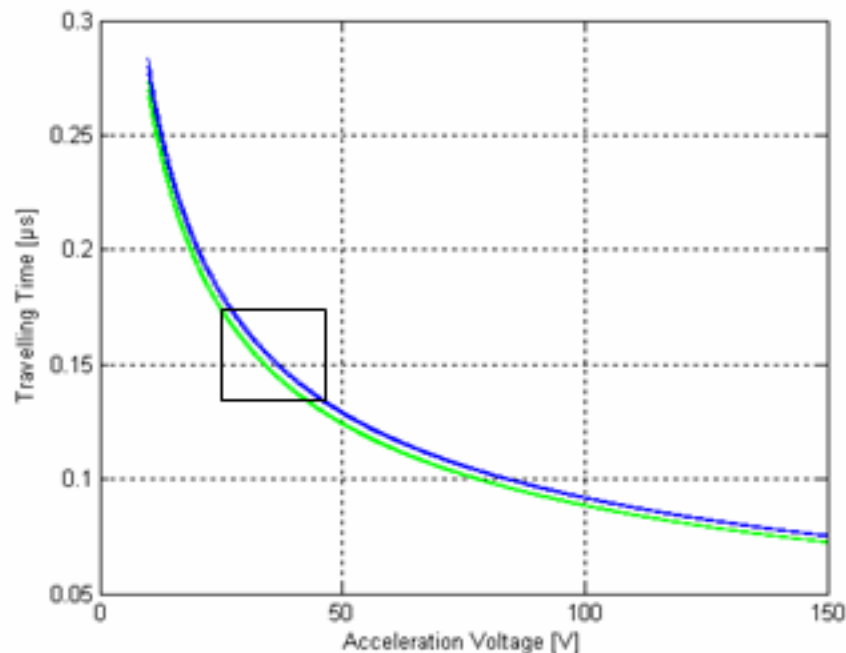


Ion Same Velocity as TDF

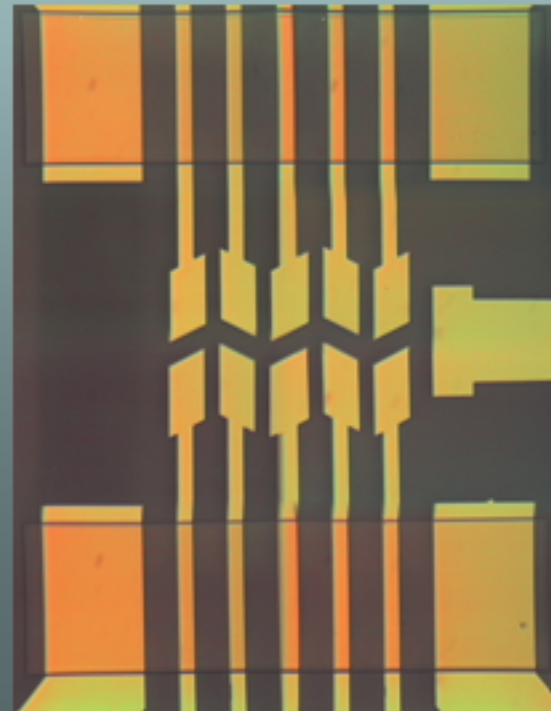
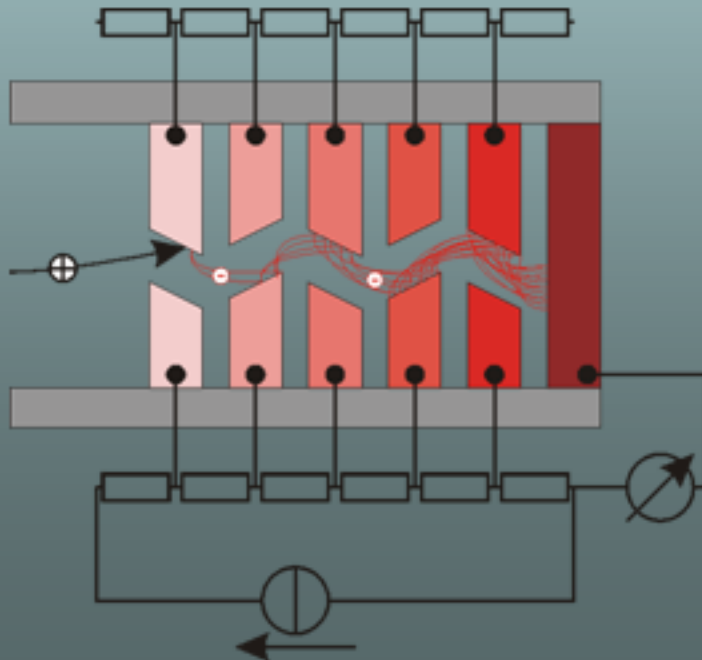
Resolution is Limited by the Thermal Velocity

$$\overline{v_{ion}} = \overline{v_e} + \overline{v_{th}} \quad \overline{v_e} = \sqrt{\frac{2e_0 U_e}{m}} \quad \overline{v_{th}} = \sqrt{\frac{8k_B T}{m\pi}}$$

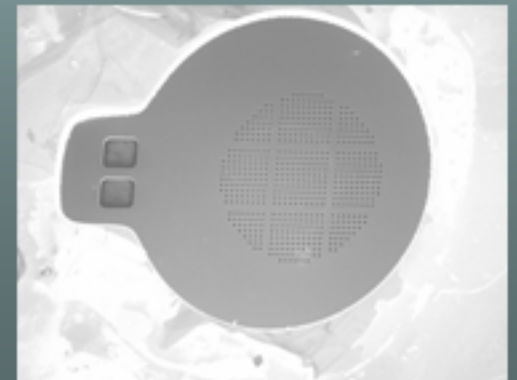
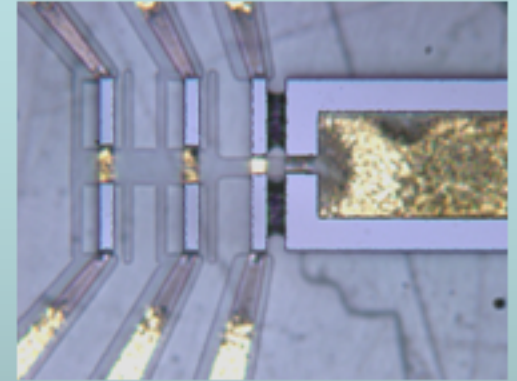
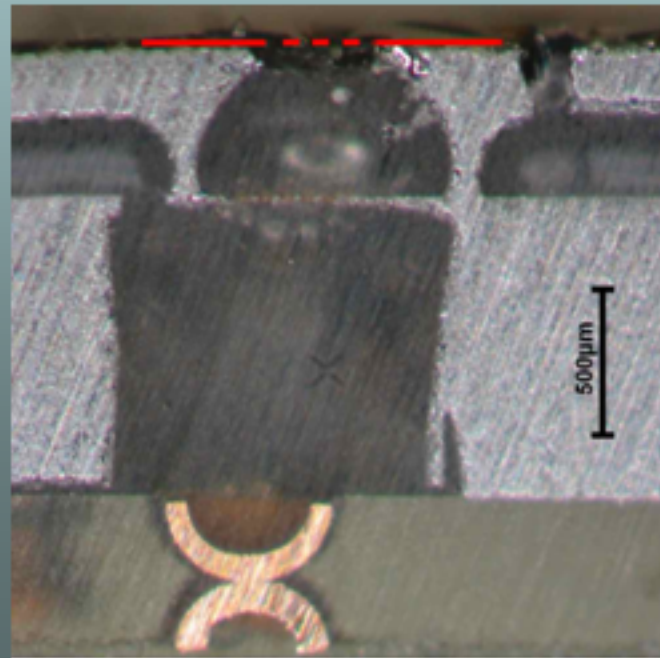
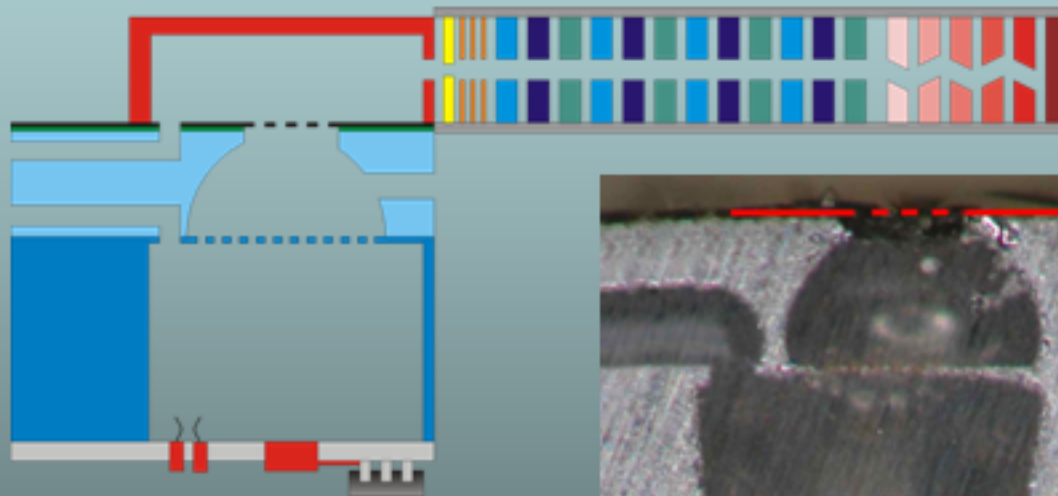
Ar M=40 from M=41



- ④ High Voltage Cascade
- ④ Integrated Thin Film Resistors ($R > 100 \text{ M}\Omega$)
- ④ Surface Coating
- ④ Ion Releases Electron Avalanche



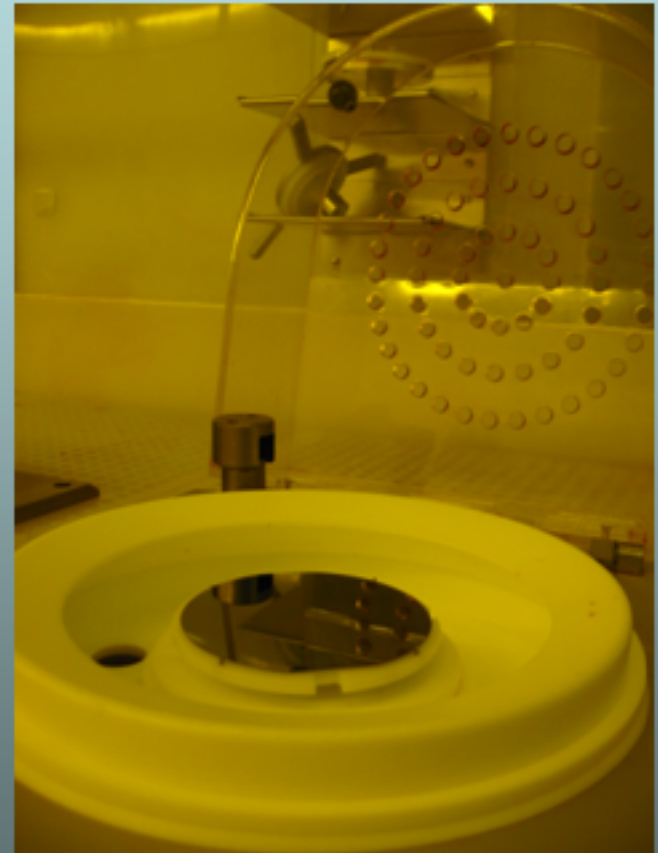
Fabrication MMS

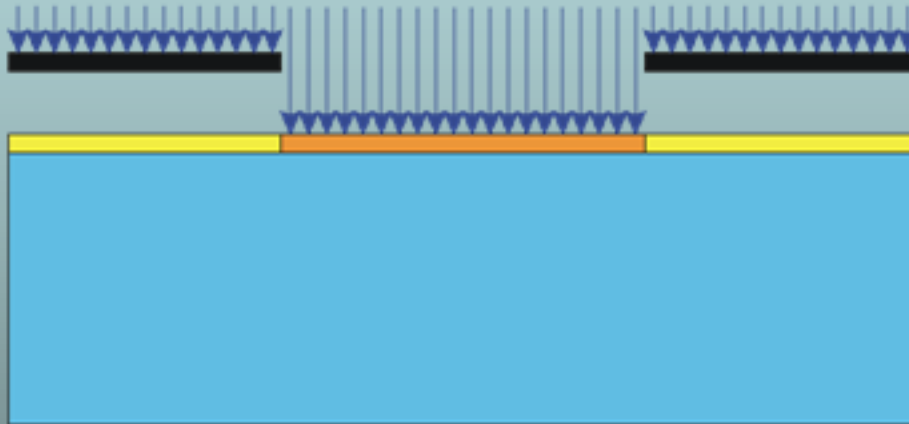


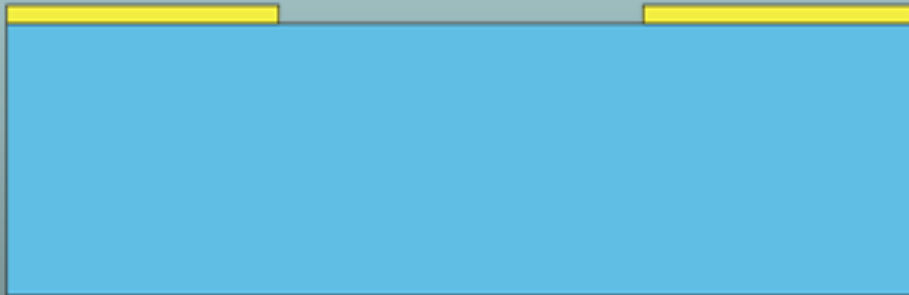
Fabrication Chamber



Fabrication Chamber







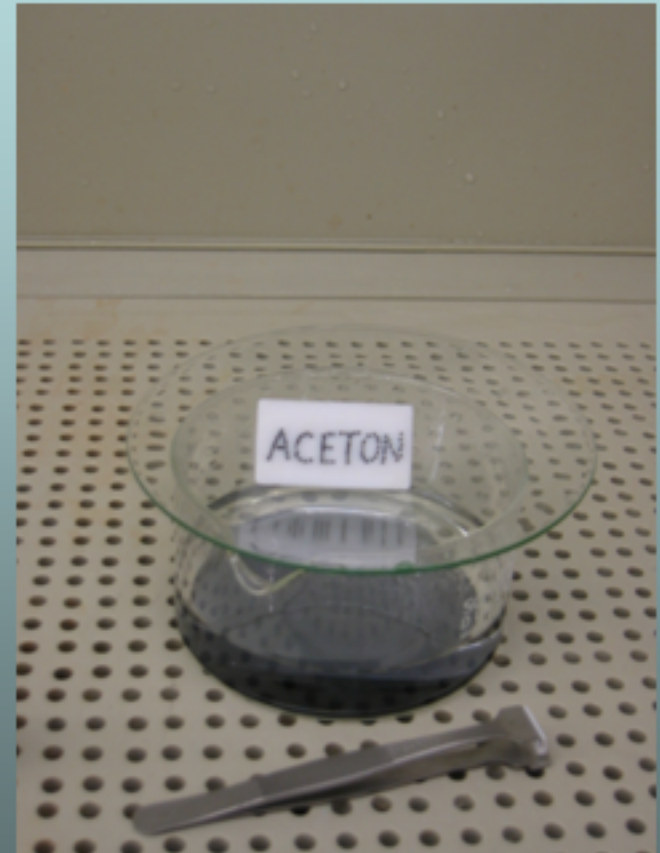








Fabrication Chamber



- ④ Small Mass Spectrometer
- ④ Fabrication by Standard Processes
- ④ New Separation Principle for MEMS Technology
- ④ Electron Source
- ④ Ion Source with Ion Optics
- ④ Build up the Mass Separator
- ④ Measure Spectrums

➤ **Fully Integrated Mass Spectrometer**

**Thanks for Your
Attention**

Acknowledgments: MMS - Team

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